

55GN01CA-TB-E Information


For Reference Only

Part Number 55GN01CA-TB-E
Manufacturer ON Semiconductor
Category Discrete Semiconductor Products
Transistors - Bipolar (BJT) - RF
Description TRANS NPN BIPOLAR 10V 70MA CP
Package TO-236-3, SC-59, SOT-23-3
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


55GN01CA-TB-E Specifications

Manufacturer Part Number	55GN01CA-TB-E
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	10V
Frequency - Transition	4.5GHz
Noise Figure (dB Typ @ f)	1.9dB @ 1GHz
Gain	9.5dB
Power - Max	200mW
DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 10mA, 5V
Current - Collector (Ic) (Max)	70mA
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	3-CP

[Report errors?](#)

55GN01CA-TB-E Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

55GN01CA-TB-E Payment Methods



55GN01CA-TB-E Shipping Methods



If you have any question about 55GN01CA-TB-E, please do not hesitate to contact us!

Website: <https://www.heisener.com>

E-mail: salesdept@heisener.com